

Solid State Devices Laboratory

Code: EC392

Contacts: 3P

Credits: 2

Module 1:

Perform any four experiments:

Ex 1: Study input characteristics of BJT in common-emitter configuration.

Ex 2: Study output characteristics of BJT in common-emitter configuration for different base currents and hence determine hybrid parameters.

Ex 3: Study output characteristics of BJT in common-emitter configuration and find performance parameters (Voltage Gain, Current Gain, Input Impedance, Output Impedance).

Ex 4: Study the variation of small-signal voltage gain with frequency of a common-emitter RC coupled amplifier.

Ex 5: Study of drain characteristics and transfer characteristics of a JFET and hence determine the FET parameters (drain resistance, transconductance & amplification factor).

Ex 6: Study the variation of small-signal voltage gain with frequency of a JFET.

Module 2:

Perform any two experiments

Ex 1: Study of C-V characteristics of a Varactor diode by appropriate software.

Ex 2: Study of C-V characteristics of a MOS structure by appropriate software.

Ex3: Study of drain characteristics and transfer characteristics of a MOSFET and hence determine the FET parameters (drain resistance, transconductance & amplification factor).